RTP Crystal

Introduction

RTP (Rubidium Titanyl Phosphate – RbTiOPO₄) is an isomorph of KTP crystal which is used in nonlinear and Electro-Optical applications. It has advantages of high damage threshold (about 1.8 times of KTP), high resistivity, high repetition rate, no hygroscopic and no induced piezo-electric effect with electrical signals up to 60 kHz. Its transmission range is 350nm to 4500nm.

Basic Properties

Crystal Structure	Orthorhombic
Cell Parameters	a = 12.96 Å; b =10.56 Å; c =6.49 Å
Mohs Hardness	About 5
Density (g/cm³)	3.6
Melting Point:	About 1000°C
Thermal Expansion Coefficients (/K)	$\alpha_x = 1.01 \times 10^{-5}, \alpha_y = 1.37 \times 10^{-5}$ $\alpha_z = -4.17 \times 10^{-6}$
Sellmeier Equations (λ in μm)	$\begin{array}{l} n_x^2 \!\!=\!\! 2.15559 + 0.93307[1\text{-}(0.20994/\lambda)^2] - 0.01452\lambda^2 \\ n_y^2 \!\!=\!\! 2.38494 + 0.73603[1\text{-}(0.23891/\lambda)^2] - 0.01583\lambda^2 \\ n_z^2 \!\!=\!\! 2.27723 + 1.11030[1\text{-}(0.23454/\lambda)^2] - 0.01995\lambda^2 \end{array}$
Thermo-optical Coefficients(dλ/dT)	-0.029 nm / ⁰ C
Electro-optic Constants(Y-cut) (X-cut)	r ₃₃ =38.5 pm/V r ₃₃ =35 pm/V, r ₂₃ =12.5 pm/V, r ₁₃ =10.6 pm/V
Electrical Resistivity	About 10 ¹¹ -10 ¹² ohm·cm
Static Half Wave Voltage at 1064 nm	4x4x20 mm: 1,600 V 6x6x20 mm: 2,400 V 9x9x20 mm: 3,600 V
Extinction Ratio	>20dB@633nm

Specifications

Growing Orientation	Along Y-axis
Maximum Length(5x5mm ² aperture)	25mm
Length Tolerance(mm)	+0.5 / -0.1
Width and Height Tolerance (mm)	±0.1
Parallelism	< 30 "
Perpendicularity	< 15'
Surface Quality	20/10
Coating	AR-coatings